

**SPD9108W**

**1 Lines, Bi-directional, Low Capacitance  
Transient Voltage Suppressors**

<http://www.sh-willsemi.com>

**Descriptions**

The SPD9108W is a low capacitance TVS (Transient Voltage Suppressor) array designed to protect high speed data interfaces. It has been specifically designed to protect sensitive electronic components which are connected to data and transmission lines from over-stress caused by Electrostatic Discharge (ESD), cable discharge events (CDE), lightning and other induced voltage surges.

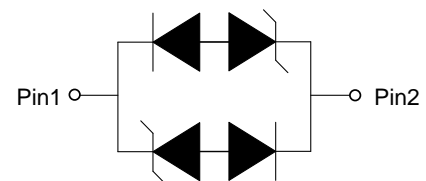
The SPD9108W incorporates low capacitance steering diodes that reduce the typical capacitance to 1.2pF per line.

The SPD9108W may be used to provide ESD protection up to  $\pm 30\text{kV}$  (contact discharge) according to IEC61000-4-2, and withstand peak pulse current up to 18A (8/20 $\mu\text{s}$ ) according to IEC61000-4-5.

The SPD9108W is available in SOD-323 package. Standard products are Pb-free and Halogen-free.



**SOD-323**



**Circuit diagram**



TA = Device code  
\* = Month code ( A~Z)

**Marking (Top View)**

**Features**

- Stand-off voltage: 8V Max.
- Transient protection for each line according to IEC61000-4-2 (ESD):  $\pm 30\text{kV}$  (contact discharge)  
IEC61000-4-4 (EFT): 40A - 5/50ns  
IEC61000-4-5 (surge): 18A (8/20 $\mu\text{s}$ ).
- Low capacitance:  $C_J = 1.2\text{pF}$  typ.
- Ultra-low leakage current:  $I_R = 1\text{nA}$  typ.
- Low clamping voltage.
- Solid-state silicon technology

**Order information**

Device	Package	Shipping
SPD9108W-2/TR	SOD-323	3000/Tape&Reel

**Applications**

- 10/100/1000 Ethernet
- STB
- Router
- Networking
- Modem

**Absolute maximum ratings**

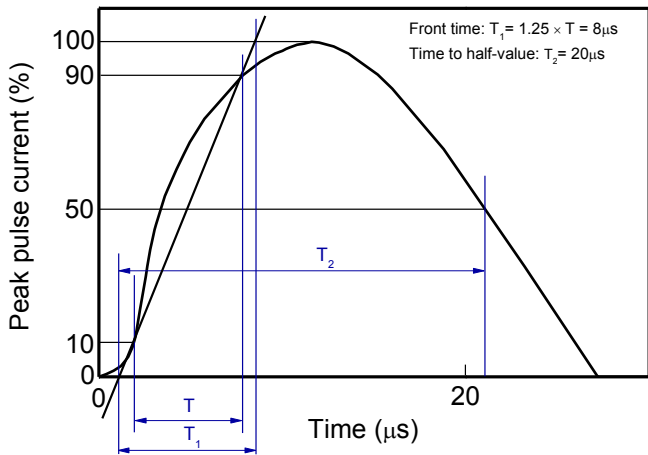
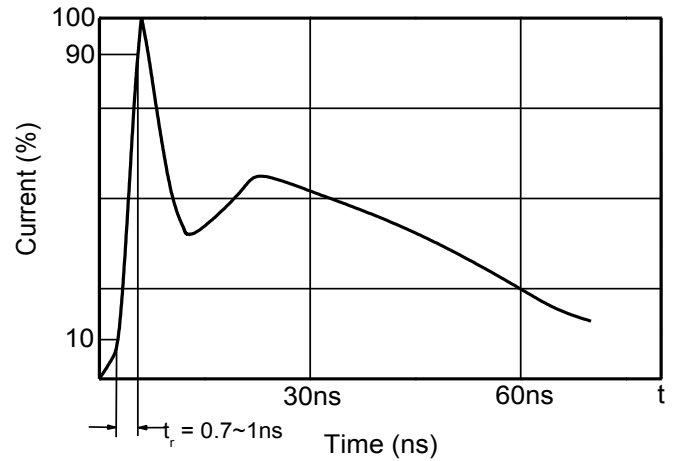
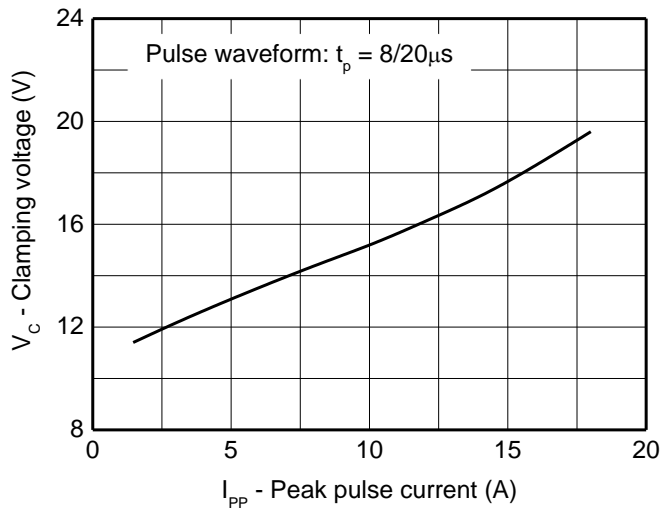
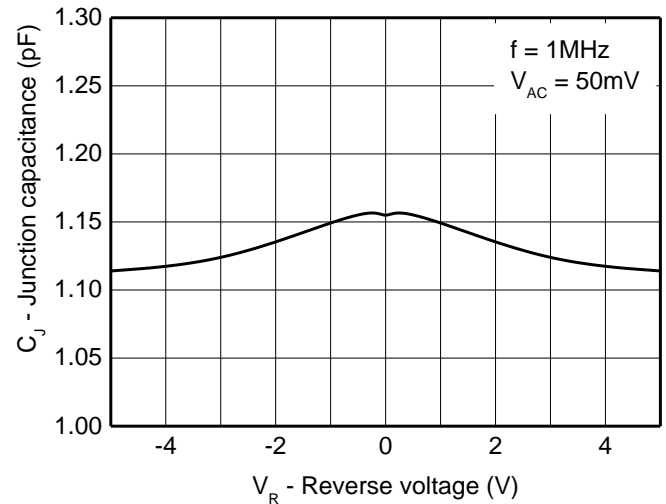
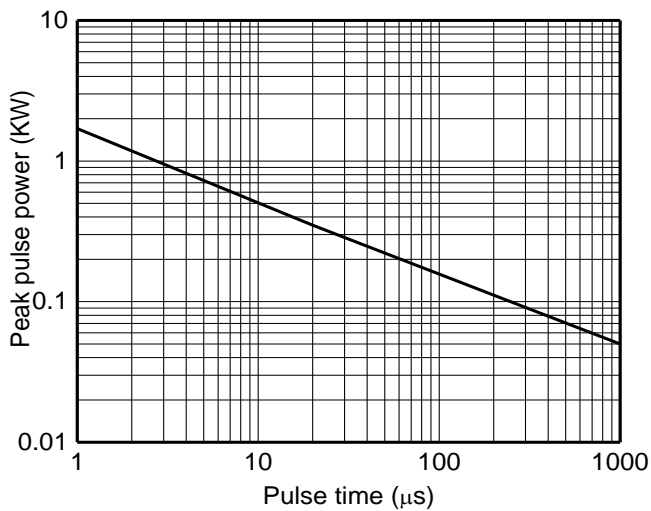
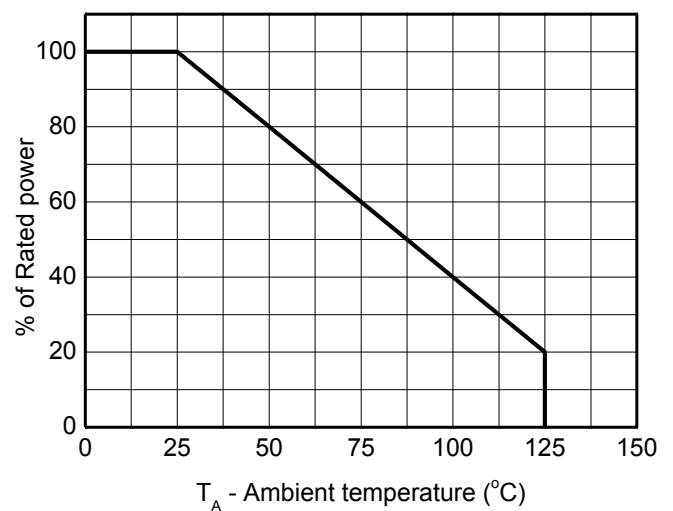
Parameter	Symbol	Rating	Unit
Peak pulse power ( $t_p = 8/20\mu s$ )	$P_{pk}$	350	W
Peak pulse current ( $t_p = 8/20\mu s$ )	$I_{pp}$	18	A
ESD according to IEC61000-4-2 air discharge	$V_{ESD}$	$\pm 30$	kV
ESD according to IEC61000-4-2 contact discharge		$\pm 30$	
Junction temperature	$T_J$	125	$^{\circ}C$
Operating temperature	$T_{OP}$	-40~85	$^{\circ}C$
Lead temperature	$T_L$	260	$^{\circ}C$
Storage temperature	$T_{STG}$	-55~150	$^{\circ}C$

**Electrical characteristics ( $T_A = 25^{\circ}C$ , unless otherwise noted)**

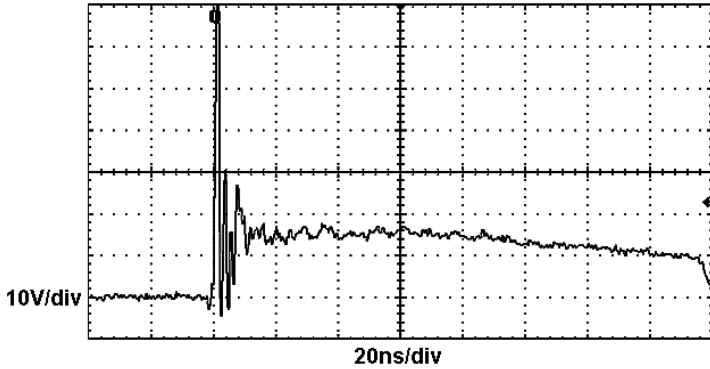
Parameter	Symbol	Condition	Min.	Typ.	Max.	Unit
Reverse maximum working voltage	$V_{RWM}$				8	V
Reverse leakage current	$I_R$	$V_{RWM} = 8V$		1	100	nA
Reverse breakdown voltage	$V_{BR}$	$I_T = 1mA$	8.5			V
Clamping voltage <sup>1)</sup>	$V_{CL}$	$I_{pp} = 1A, t_p = 8/20\mu s$			12	V
		$I_{pp} = 5A, t_p = 8/20\mu s$			15	V
		$I_{pp} = 18A, t_p = 8/20\mu s$			24	V
Junction capacitance	$C_J$	$V_R = 0V, f = 1MHz$		1.2	1.8	pF

Notes:

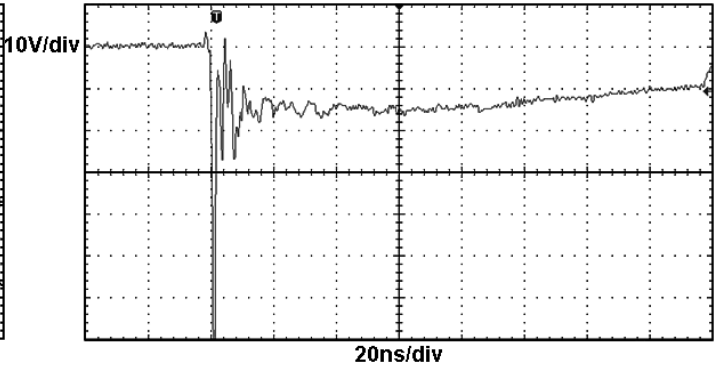
1) Non-repetitive current pulse, according to IEC61000-4-5.

**Typical characteristics ( $T_A = 25^\circ\text{C}$ , unless otherwise noted)**

**8/20 $\mu\text{s}$  waveform per IEC61000-4-5**

**Contact discharge current waveform per IEC61000-4-2**

**Clamping voltage vs. Peak pulse current**

**Capacitance vs. Reverse voltage**

**Non-repetitive peak pulse power vs. Pulse time**

**Power derating vs. Ambient temperature**

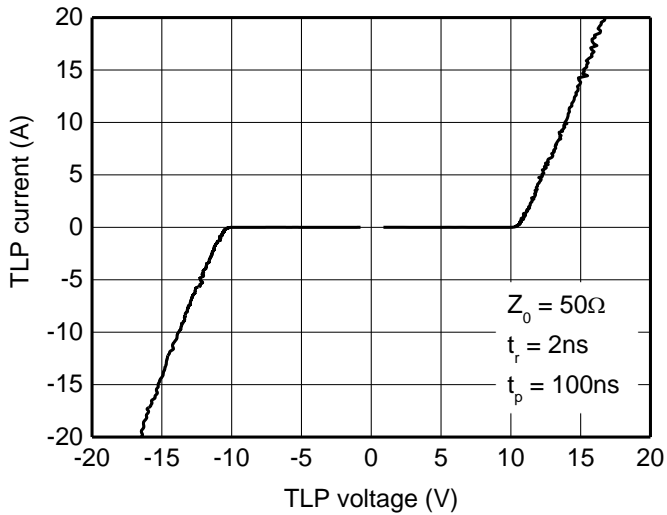
Typical characteristics ( $T_A=25^\circ\text{C}$ , unless otherwise noted)



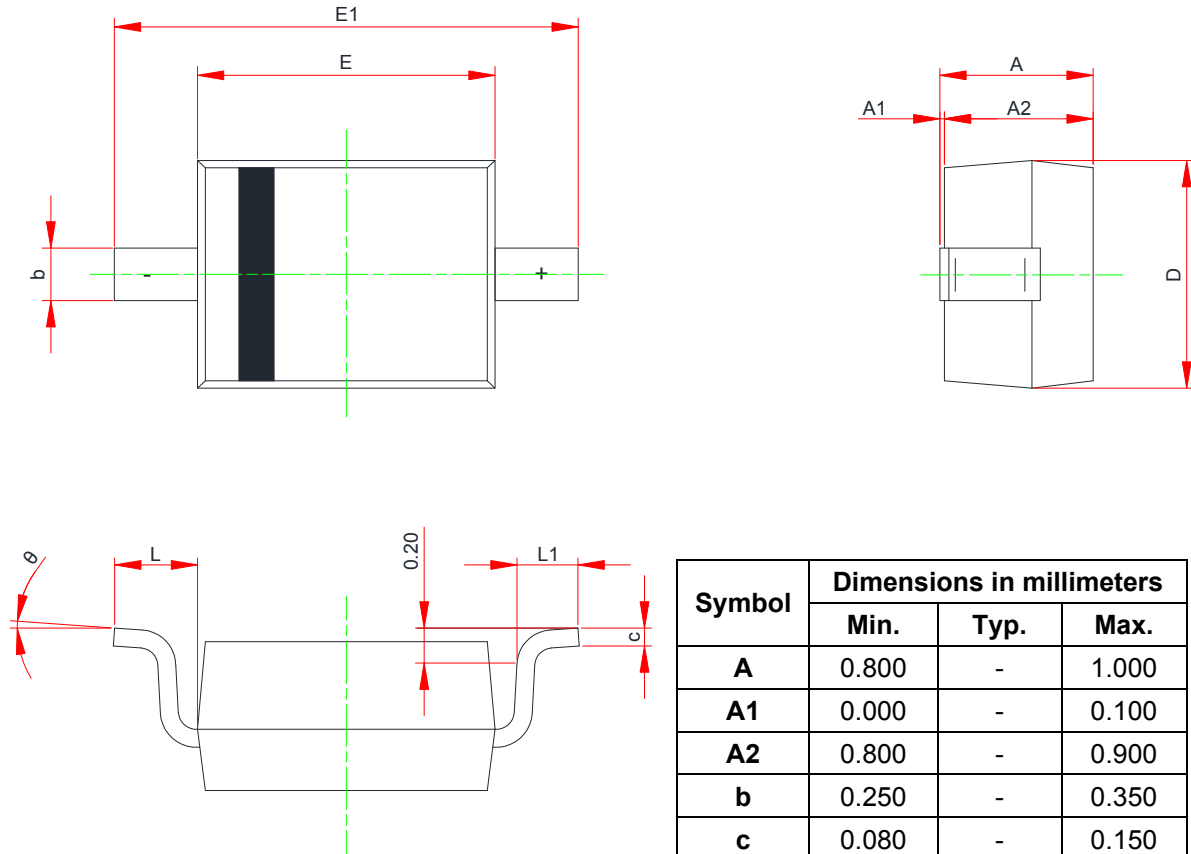
**ESD clamping**  
 (+8kV contact discharge per IEC61000-4-2)



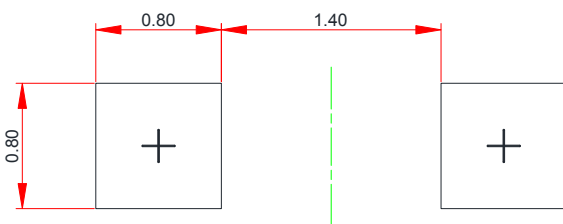
**ESD clamping**  
 (-8kV contact discharge per IEC61000-4-2)



**TLP Measurement**

**Package outline dimensions**
**SOD-323**


Symbol	Dimensions in millimeters		
	Min.	Typ.	Max.
<b>A</b>	0.800	-	1.000
<b>A1</b>	0.000	-	0.100
<b>A2</b>	0.800	-	0.900
<b>b</b>	0.250	-	0.350
<b>c</b>	0.080	-	0.150
<b>D</b>	1.200	-	1.400
<b>E</b>	1.600	-	1.800
<b>E1</b>	2.500	-	2.700
<b>L</b>	0.475 REF		
<b>L1</b>	0.250	-	0.400
<b>θ</b>	0°	-	8°

**Recommend land pattern (Unit: mm)**

**Notes:**

This recommended land pattern is for reference purposes only. Please consult your manufacturing group to ensure your PCB design guidelines are met.